



Harald Lück, AEI Hannover

EU contract #211743

ET- EINSTEIN TELESCOPE

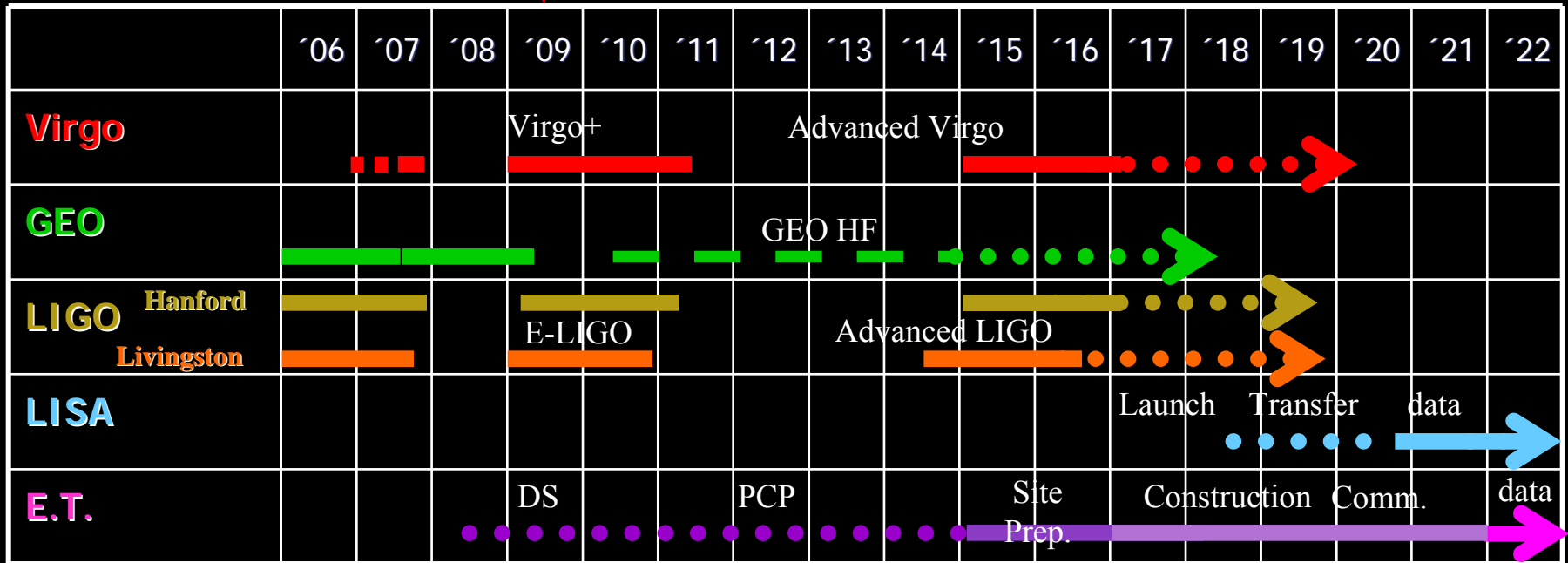
TECHNOLOGY FOR THE THIRD GENERATION



GW Timelines



You are here



1st Generation

2nd Generation

3rd Gen.



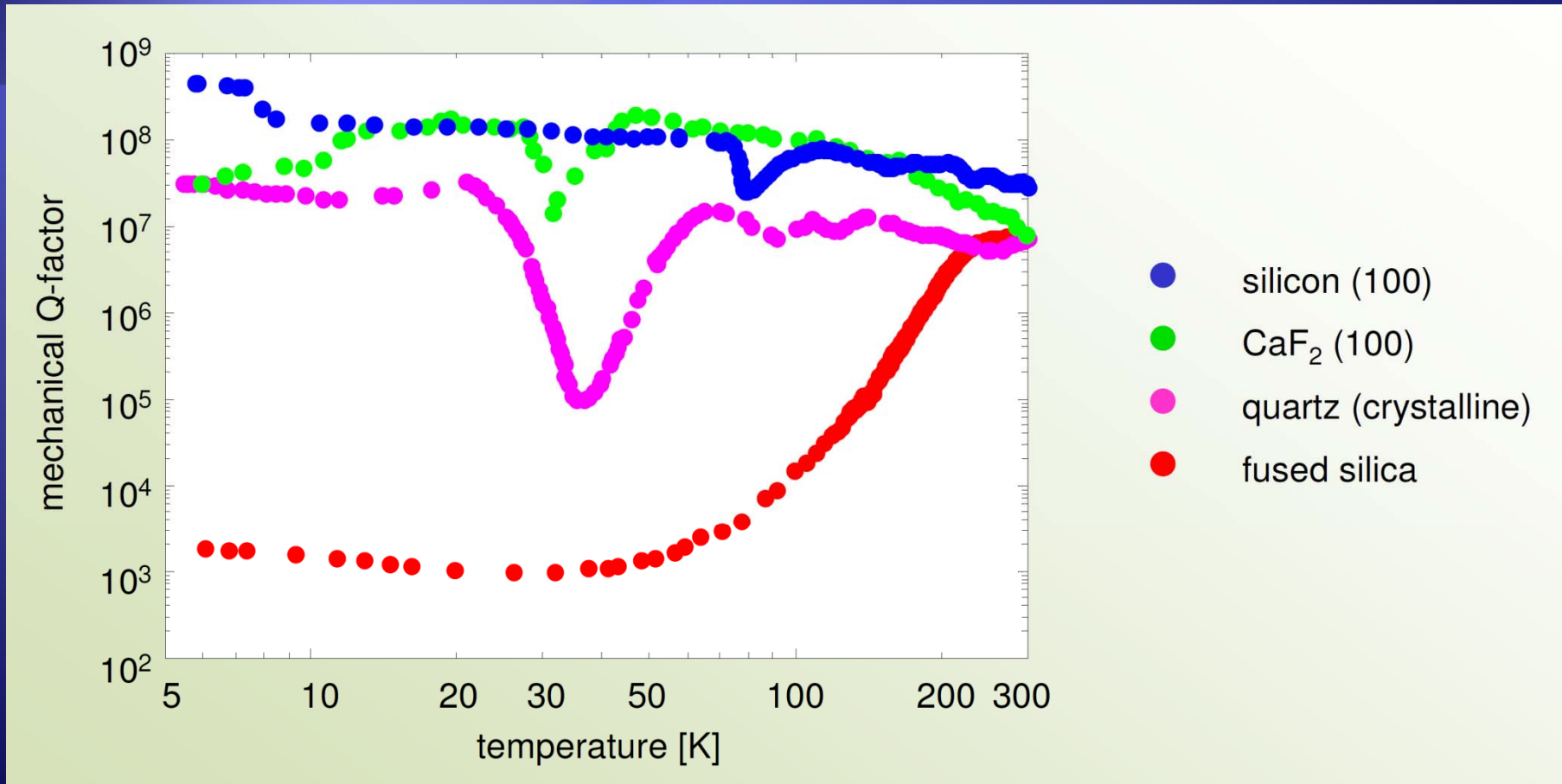
In this talk no discussion of

- ◆ Interferometer size
 - As big a finances allow? How big is that?
- ◆ Over-ground vs under-ground (J. Harms, Jo Van der Brand, D. Rabeling)
 - Will low frequency performance goals really require underground operation ?
- ◆ Low frequency suspensions (R. Nawrodt)
- ◆ ~~Newtonian Noise~~
- ◆ Cryogenic operation (W. Johnson, K. Kuroda)
 - Is cryogenics really needed to achieve the goals or is room temperature sufficient (at least for high frequencies) ?
- ◆ Non gaussian beams (A. Freise)
- ◆ QND tricks (H. Müller-Ebhardt)
- ◆ Xylophone: colocated multi-narrowband vs single-broadband detector (S. Hild, R. DeSalvo)

Some (good?) candidates for the third generation

- ◆ Substrate material: Silicon
- ◆ Gratings & wave-guide coatings (H. Lück)
- ◆ Quantum noise:
 - ◆ Squeezing (A. Khalaidovski)
 - ◆ Laser (N. Man)

Mechanical Q of substrate materials

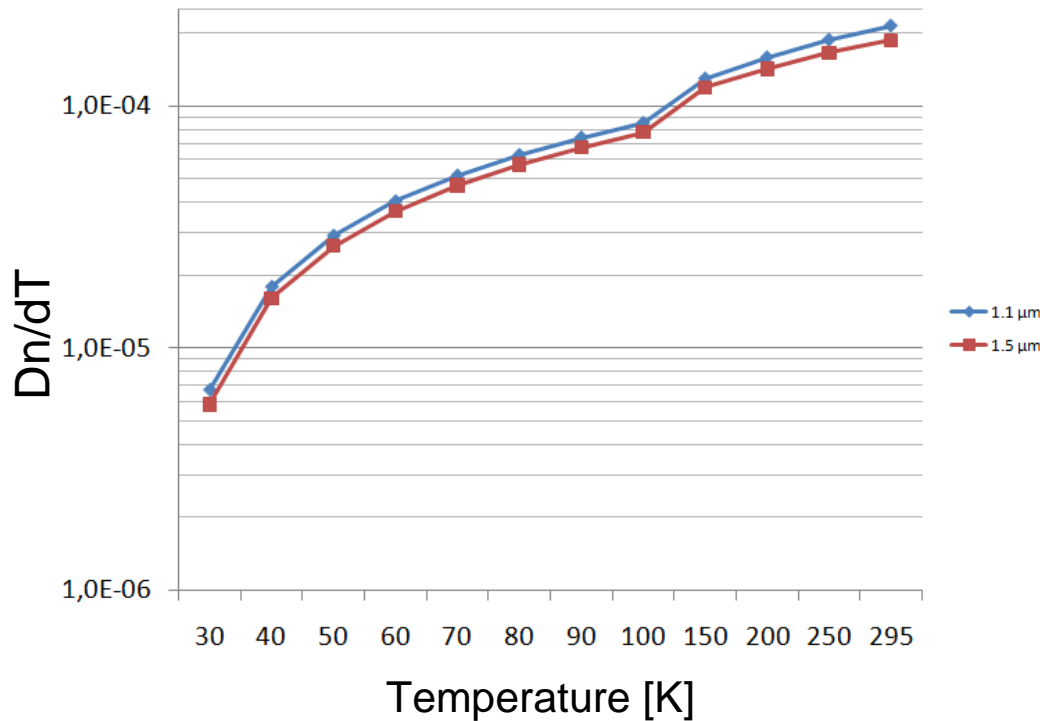


Nawrodt et al.

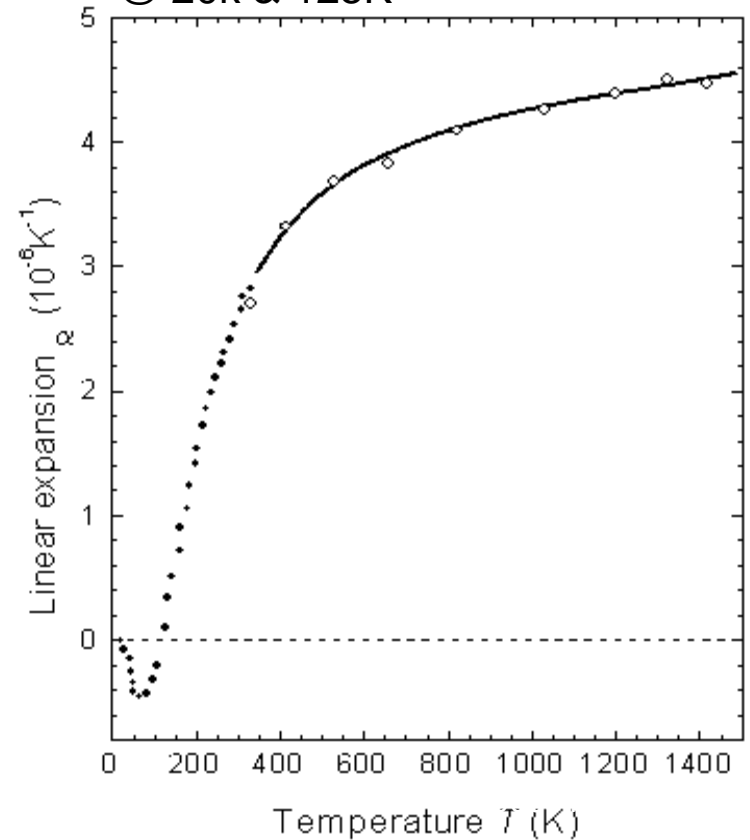
SILICON (Properties)

Low thermal lensing @ low temp.
Fused silica $2E-5 / K$ @ 300 K

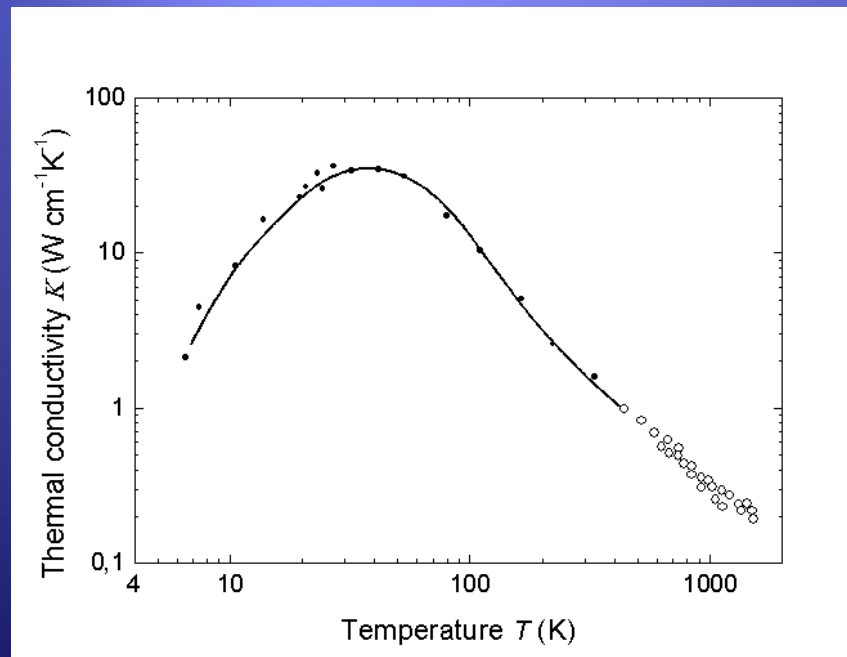
No thermoelastic noise



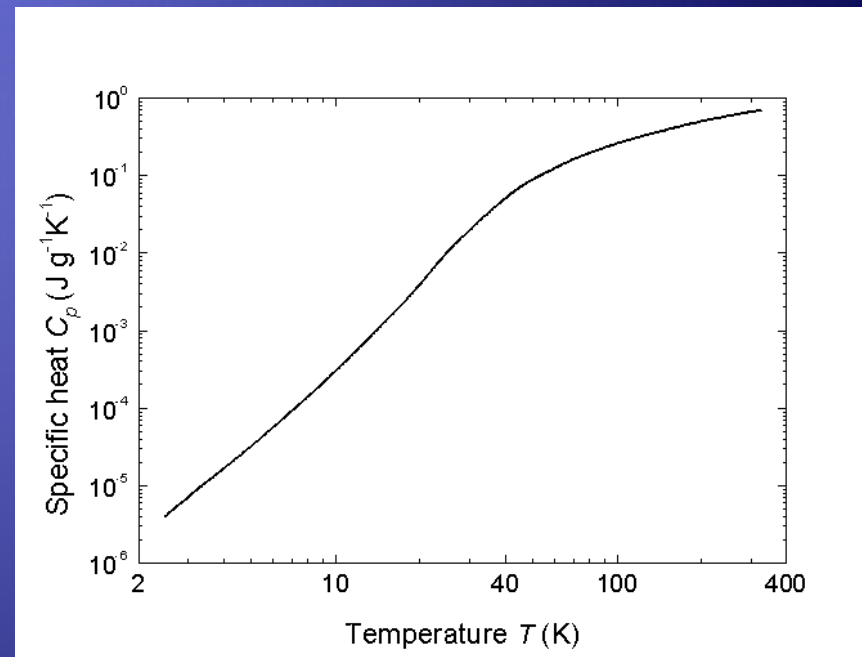
Vanishing CTE @ 20k & 125K



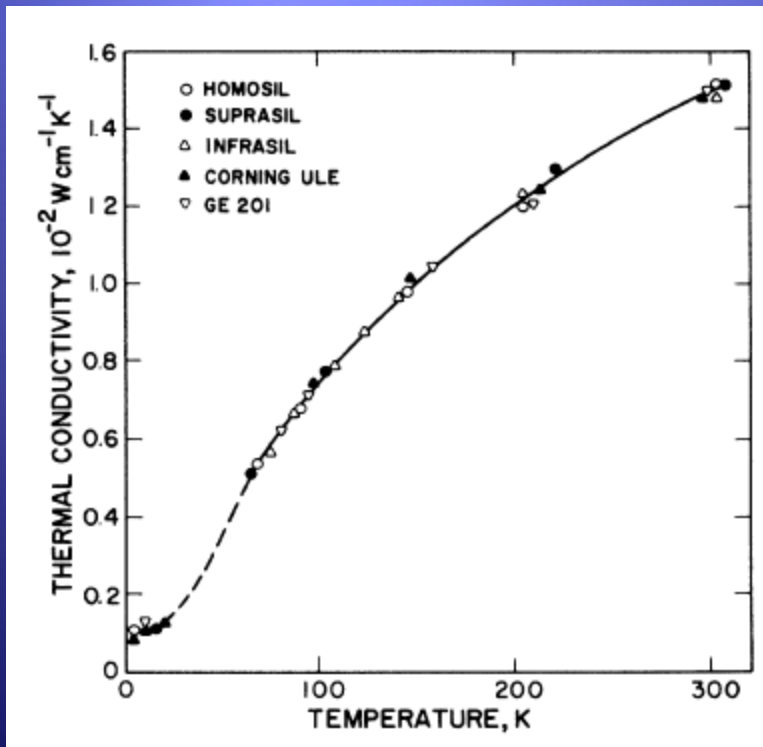
Thermal conductivity Silicon



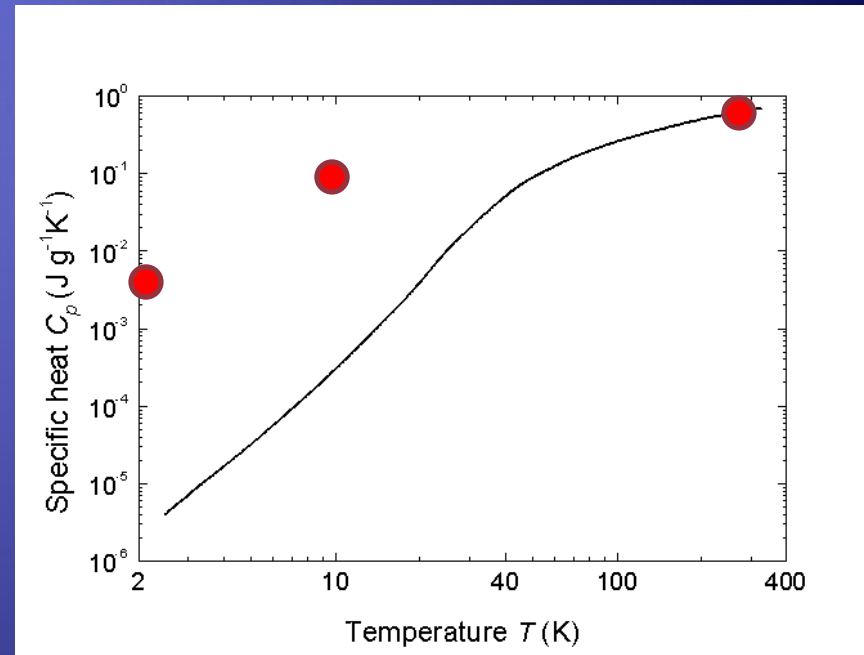
Specific heat Silicon



Thermal conductivity fused Silica



Specific heat Silicon / fused silica

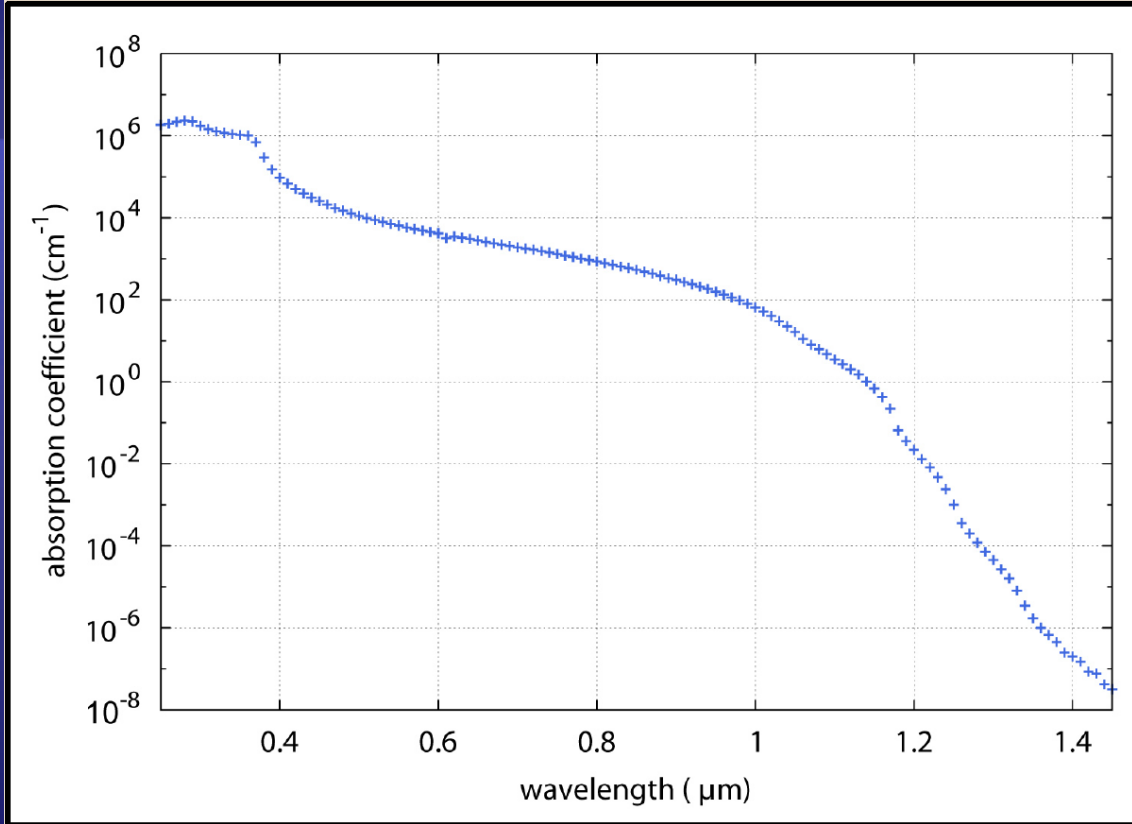


1E4

1/10

Silicon

low absorption @ 1550nm expected



from M. Green and M. Keevers, Optical properties of intrinsic Silicon @ 300K, Progress in Photovoltaic research and Applications, Vol. 3, 189-192 (1995)



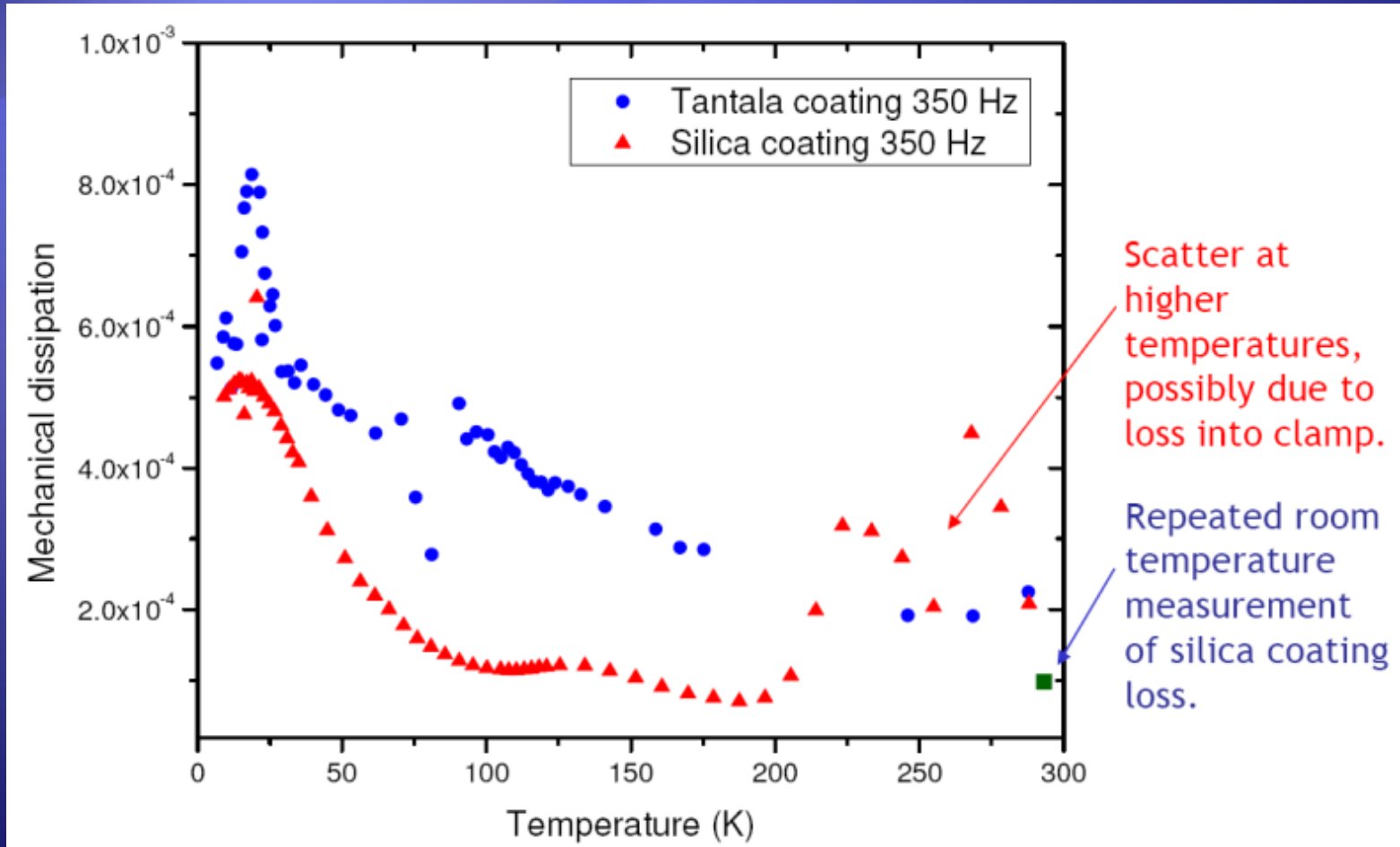
Max. Diameter currently 450mm

Wikipedia.com
G0900631-v1



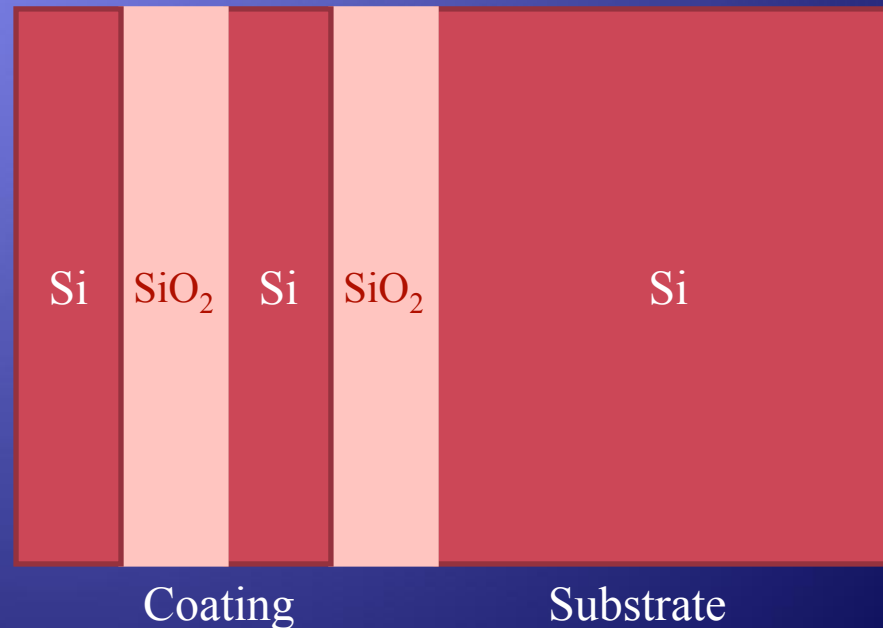
Mechanical losses

of the coatings



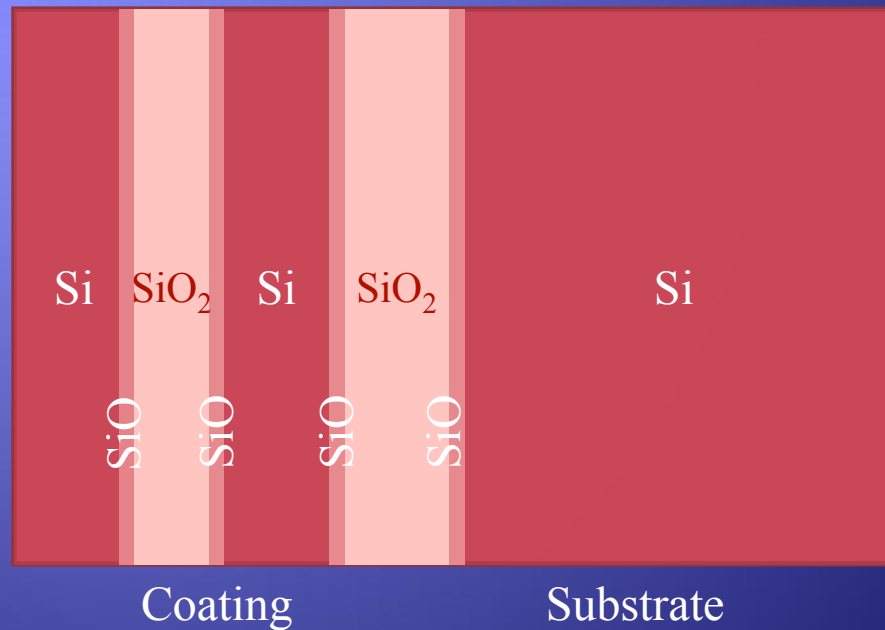
Coatings on Silicon

- ◆ Refractive index of Silicon @ 1550nm ~ 3.48 @ 300K
- ◆ Refractive Index of SiO₂ ~ 1.44
- ◆ fewer layers needed due to difference in refractive indices



Diffusion of Oxygen

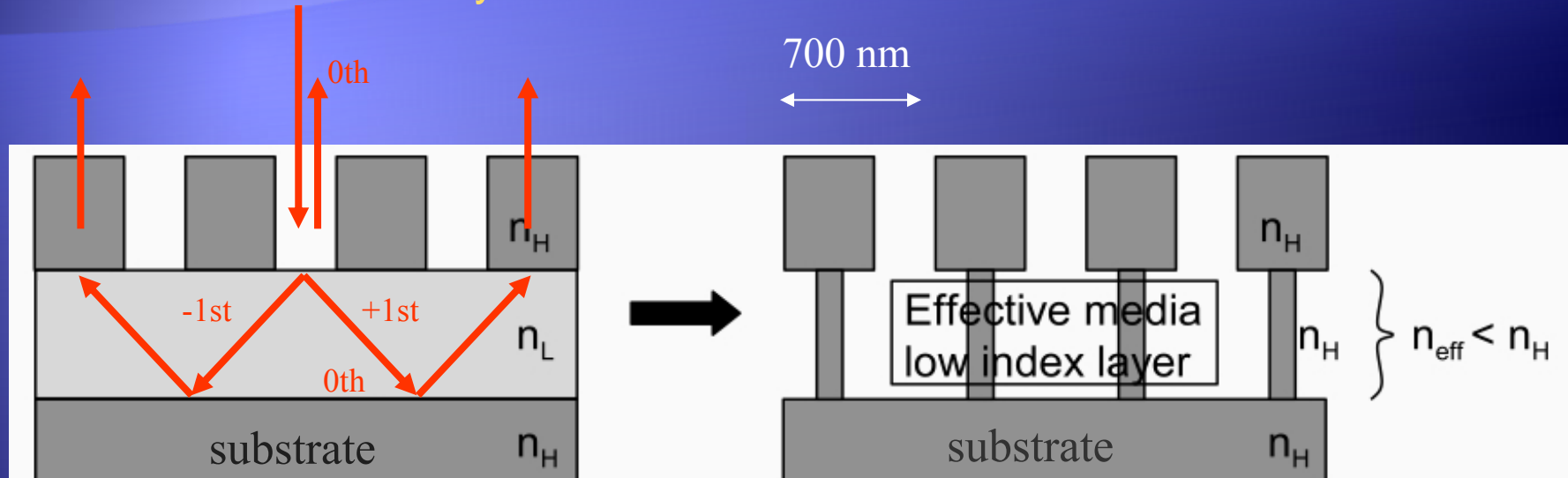
High absorption of SiO might be a problem for SiO₂ coatings on Silicon substrates



Nanostructured Surfaces

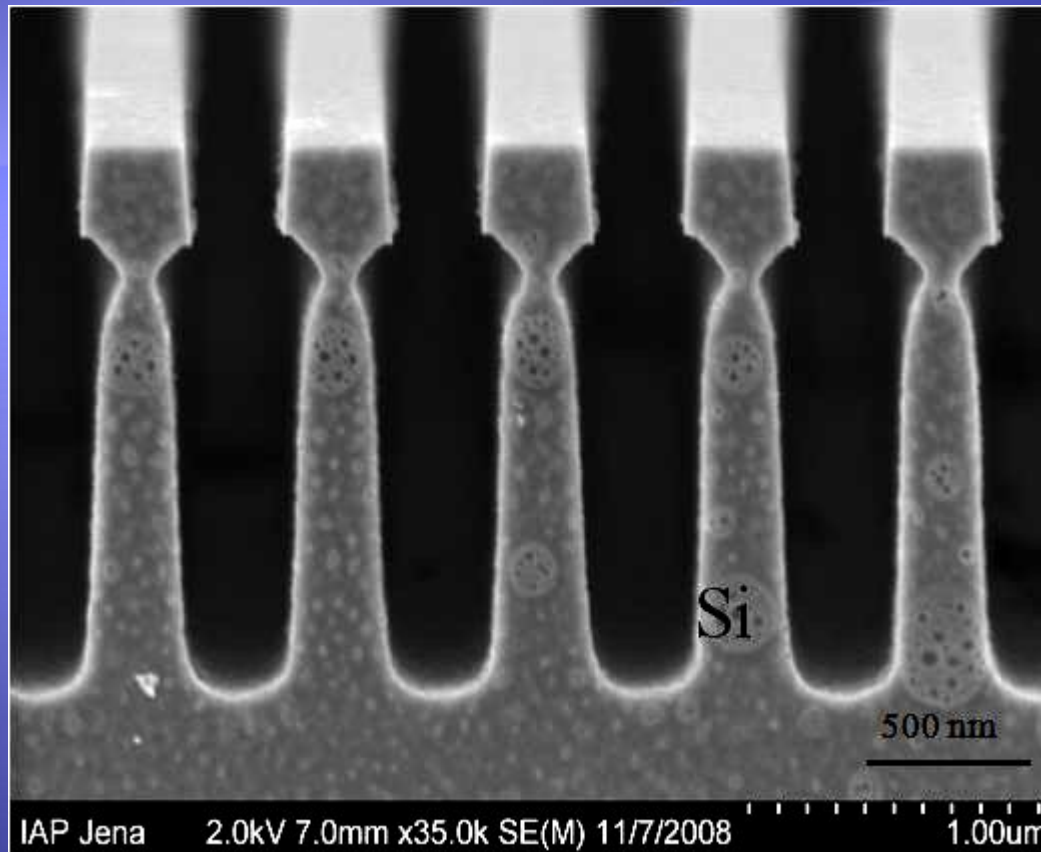
waveguide coatings

'100%' reflectivity



Monolithic 100% reflection "coating"
[Brückner *et al.*, Opt. Lett., 33, 264 (2008)]

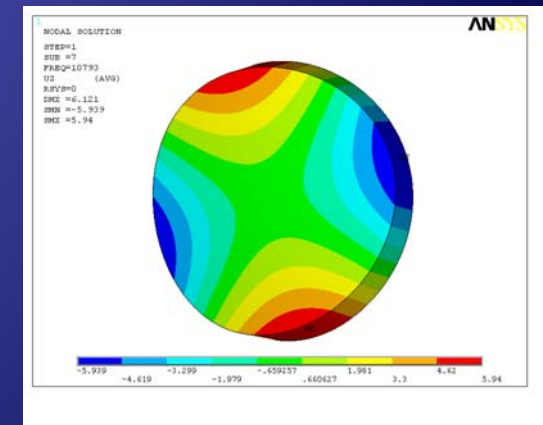
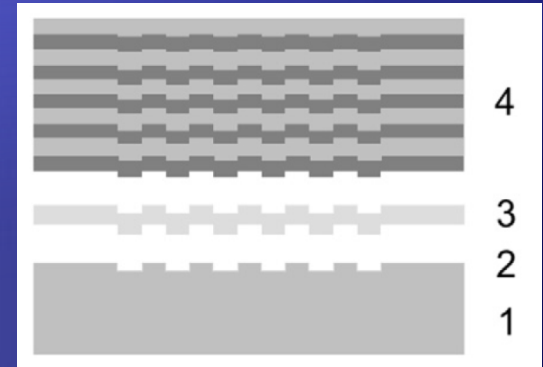
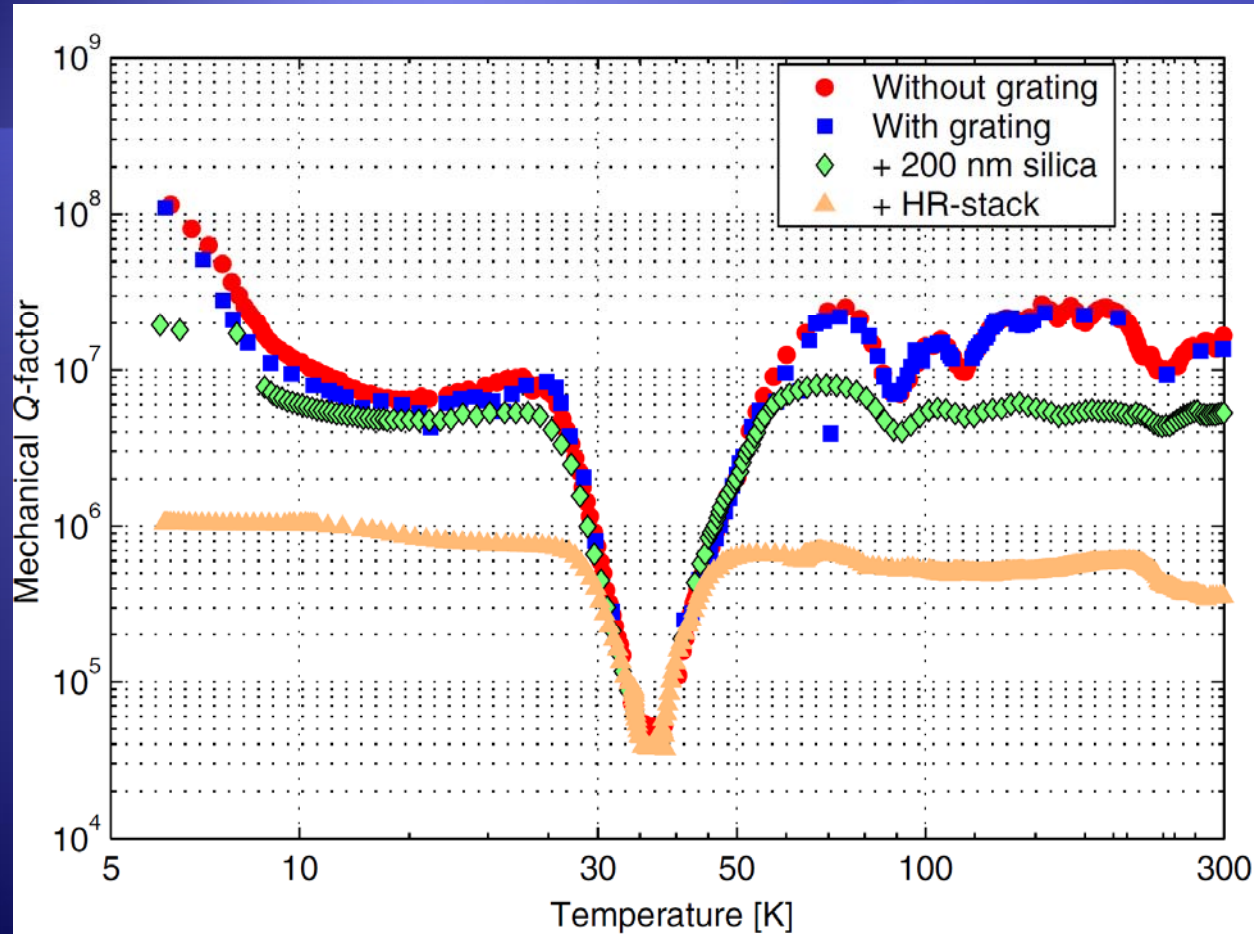
Promising new results



R > 99.8%, private communication, IAP Jena, R. Schnabel

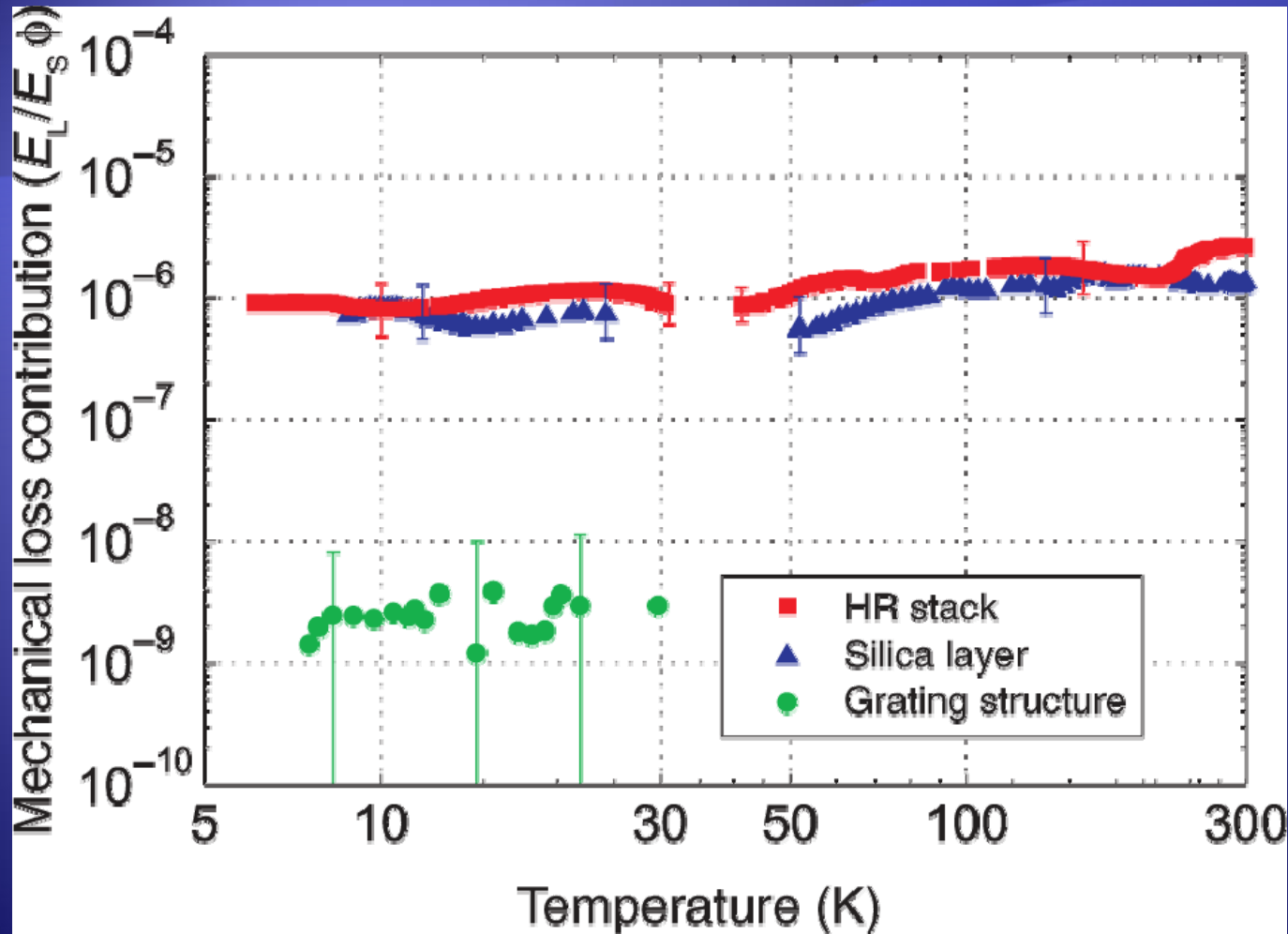
Mechanical losses of gratings

Nawrodt et al., New Journal of Physics 9 (2007) 225



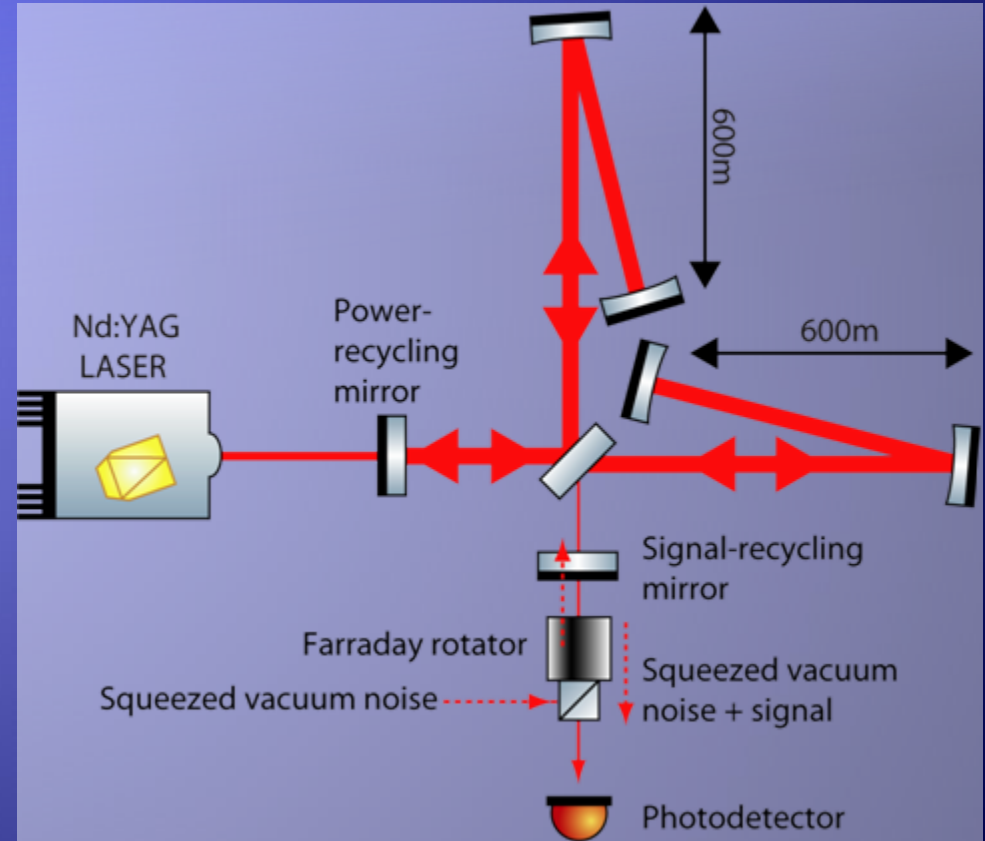
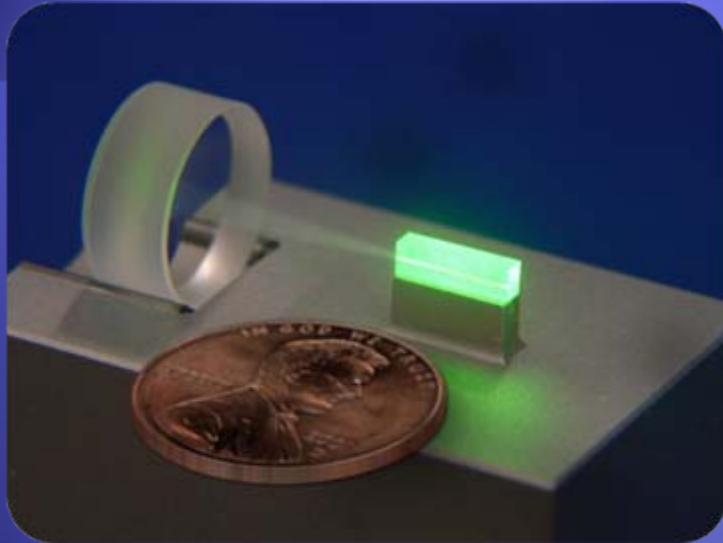
cryst. quartz, \varnothing 3" \times 12 mm, 11670 Hz

Extracted coating/grating losses



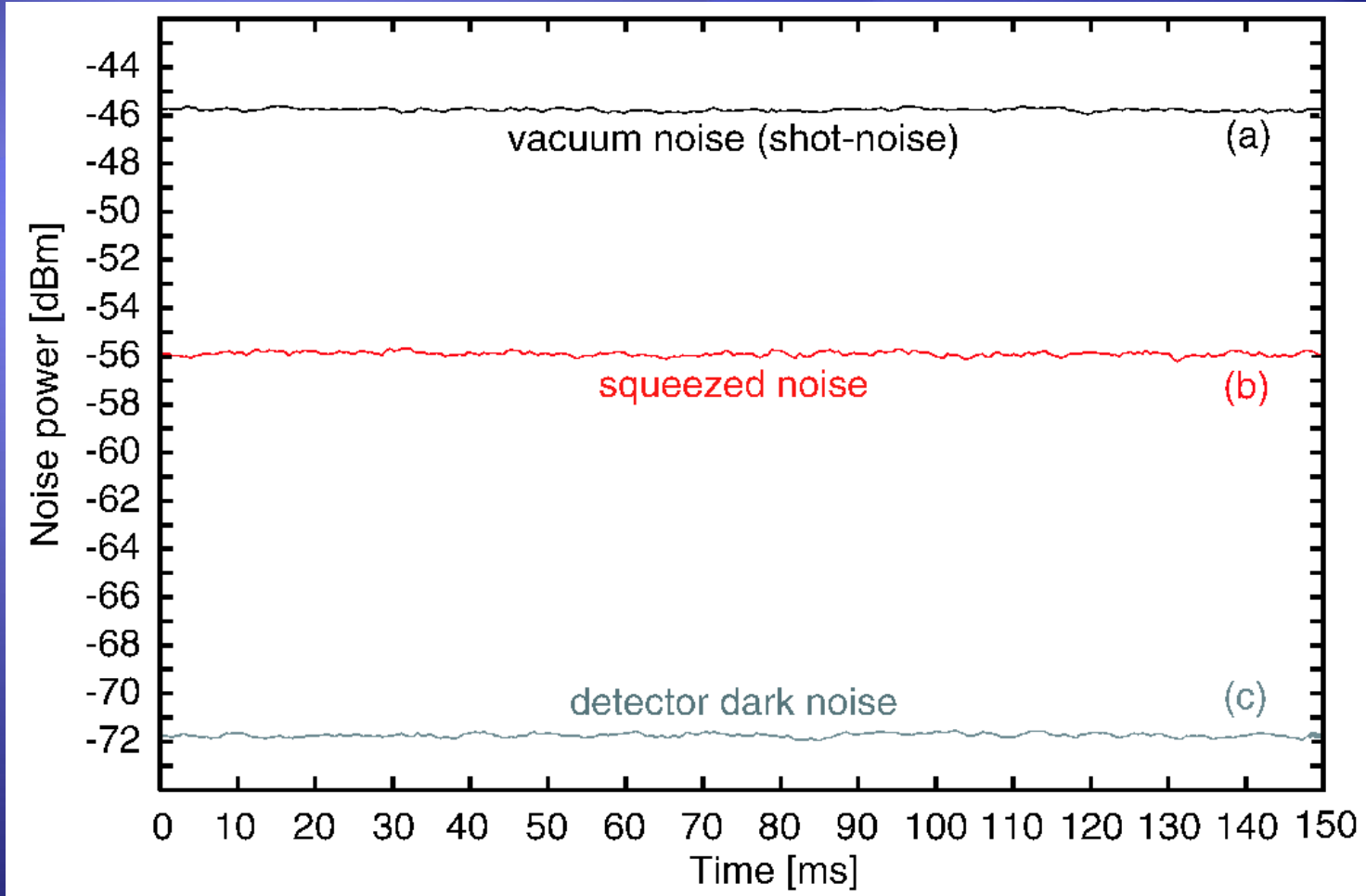
Nawrodt et al., New Journal of Physics 9 (2007) 225

Squeezing



11.5dB @ 5MHz

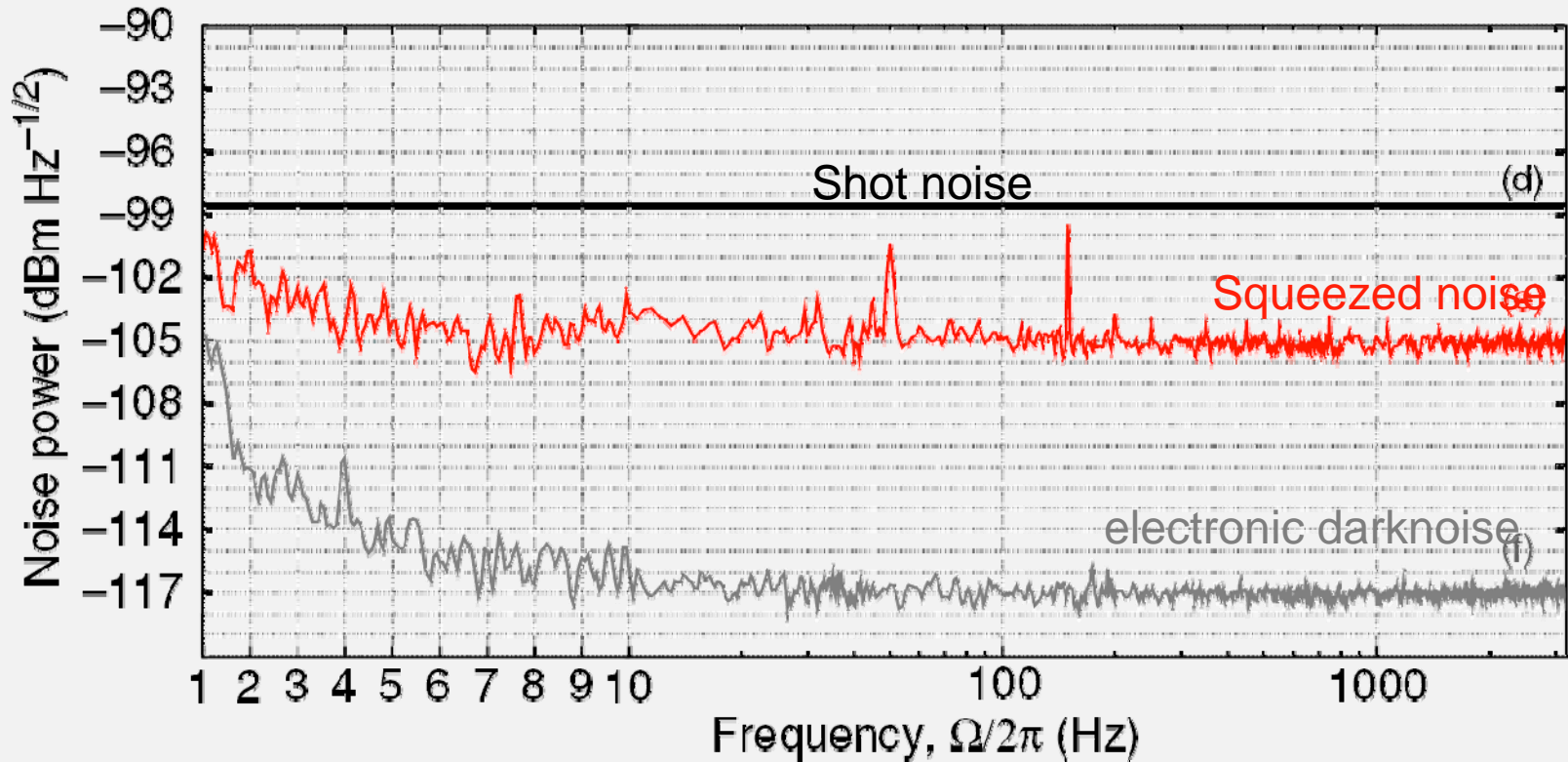
1064 nm



Vahlbruch et al. PRL 100, 033602 (2008)

Low frequency squeezing

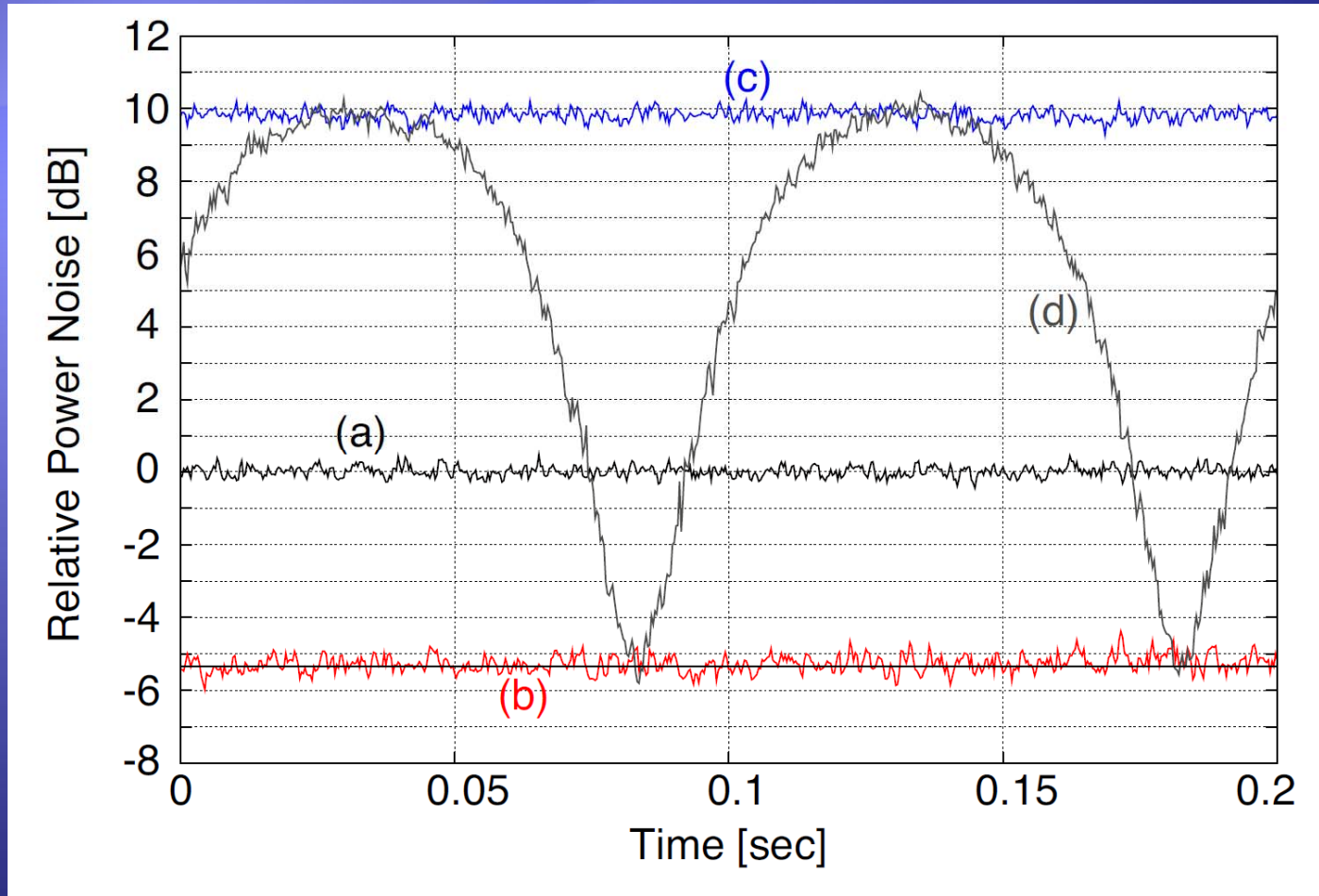
1064 nm



Chelkowski *et al.*, PRA 75, 043814 (2007)

Squeezing @ 1550 nm

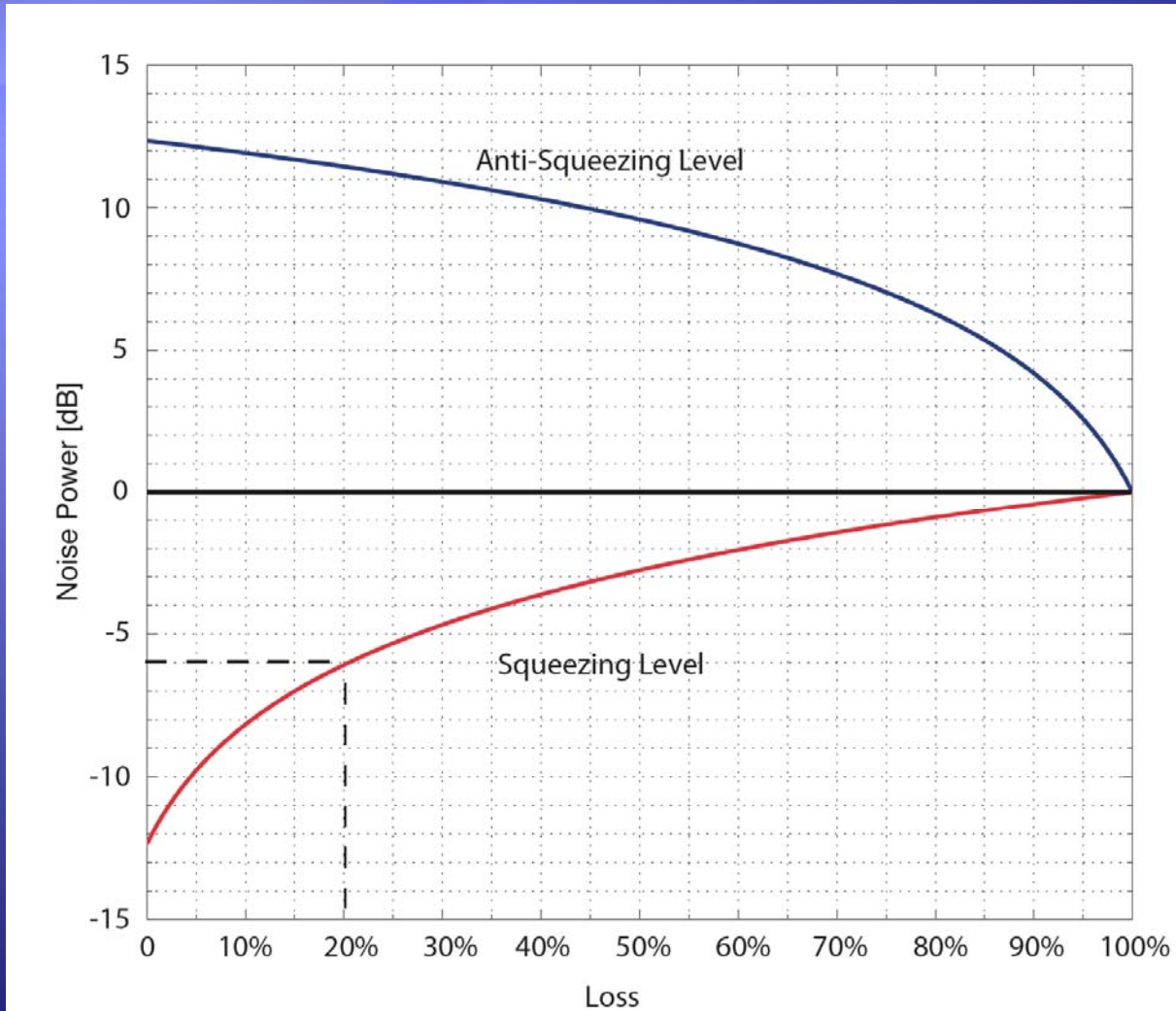
1550 nm



Mehmet et. al.: arXiv:0902.0670v1 [quant-ph]

Fragile Squeezed States

Influence of losses



available today, 1064 nm

- ◆ Solid state laser:
 - ◆ laser diode pumped solid state laser (AdvLIGO):
 - ◆ **210W** Nd:YAG, less than 12% in higher order modes, almost finished design for reliable long-term operation
 - ◆ $3 \text{ E-9} / \sqrt{\text{Hz}}$ power stability @ 10Hz, rf noise: 1dB above SN of 100mA @ 9 MHz
- ◆ fibre laser:
 - ◆ ytterbium doped photonic crystal fiber amplifier using a single-frequency Nd:YAG non-planar ring oscillator seed source
 - ◆ **148W**, less than 8% in higher order modes
 - ◆ 13 November 2006 / Vol. 14, No. 23 / OPTICS EXPRESS 11071

available today, 1550 nm

- ◆ Solid state laser:
 - ◆ -
- ◆ fibre laser:
 - ◆ Erbium fibre laser, ~ 2 W, poor reliability

Laser plans

- ◆ 1064 nm:
 - ◆ Reach 1kW within next 5 years
 - ◆ $RIN < 1 \text{ E-9} / \sqrt{\text{Hz}}$
- ◆ 1550 nm:
 - ◆ 150 W within next few years

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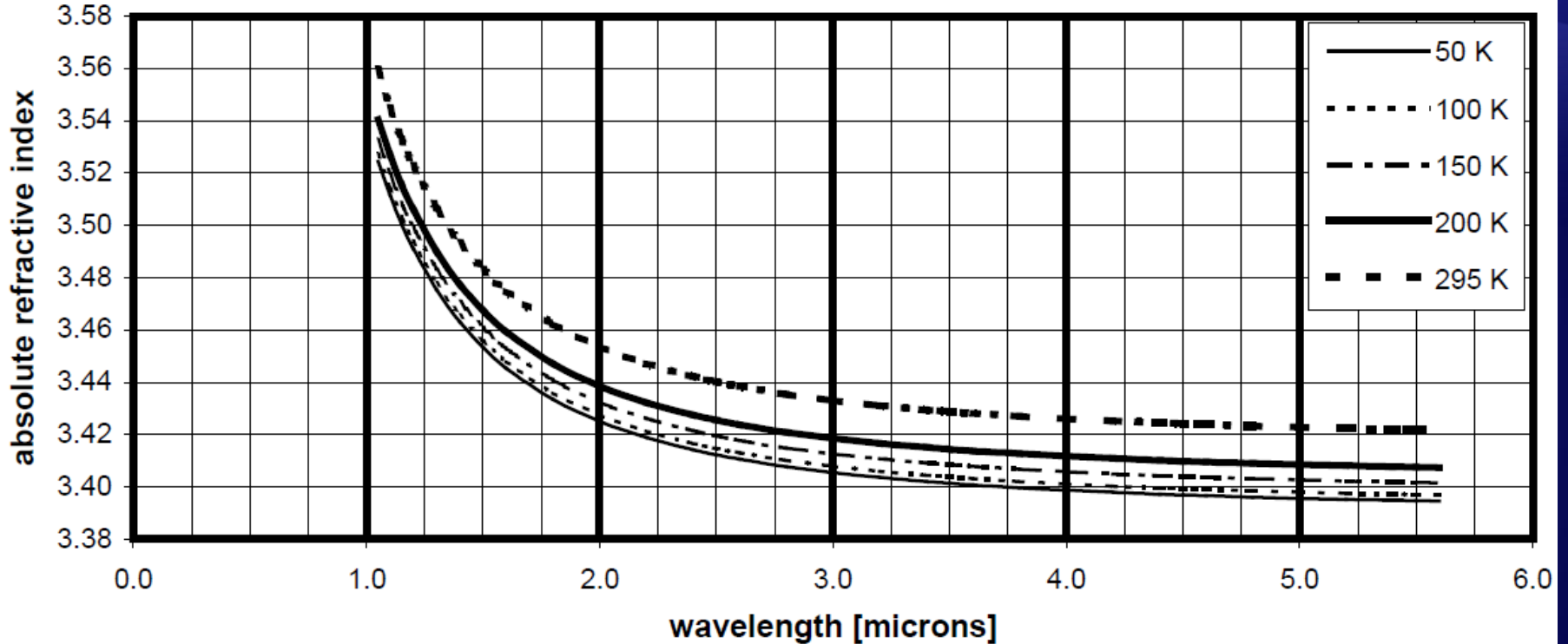
gravitational wave observatory

CENTR



Refractive index of silicon

Absolute refractive index of silicon with temperature



Temperature-dependent refractive index of silicon and germanium

Bradley J. Frey*, Douglas B. Leviton, Timothy J. Madison
NASA Goddard Space Flight Center, Greenbelt, MD 20771

Refractive Index fused silica



<http://www.sciner.com/Opticsland/FS.htm>

Wavelength , μm	0.2	0.22	0.25	0.3	0.32	0.36	0.4	0.45	0.5	
Refractive Index	1.55051	1.52845	1.50745	1.48779	1.48274	1.47529	1.47012	1.46557	1.46233	
Wavelength , μm	0.55	0.59	0.60	0.65	0.7	0.75	0.8	0.85	0.9	
Refractive Index	1.46008	1.45846	1.45804	1.45653	1.45529	1.45424	1.45332	1.4525	1.45175	
Wavelength , μm	1.0	1.1	1.2	1.3	1.5	1.6	1.7	1.8	1.9	2.0
Refractive Index	1.45042	1.4492	1.44805	1.44692	1.44462	1.44342	1.44217	1.44087	1.43951	1.43809



The brute force approach

Stefan Hild

